# **1.1 GHz Prescaler**

# Description

The MC12080 is a single modulus divide by 10, 20, 40, 80 prescaler for low power frequency division of a 1.1 GHz high frequency input signal. Divide ratio control inputs SW1, SW2 and SW3 select the required divide ratio of  $\pm 10$ ,  $\pm 20$ ,  $\pm 40$ , or  $\pm 80$ .

An external load resistor is required to terminate the output. An 820  $\Omega$  resistor is recommended to achieve a 1.2 V<sub>pp</sub> output swing, when dividing a 1.1 GHz input signal by the minimum divide by ratio of 10, assuming a 8.0 pF load. Output current can be minimized dependent on conditions such as output frequency, capacitive load being driven, and output voltage swing required. Typical values for load resistors are included in the V<sub>out</sub> specification for various divide ratios at 1.1 GHz input frequency.

# Features

- 1.1 GHz Toggle Frequency
- Supply Voltage 4.5 to 5.5 V
- Low Power 3.7 mA Typical at  $V_{CC} = 5.0 V$
- Operating Temperature Range of -40 to 85°C
- These Devices are Pb-Free and are RoHS Compliant

## Table 1. MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage, Pin 2	V <sub>CC</sub>	–0.5 to 7.0	Vdc
Operating Temperature Range	T <sub>A</sub>	-40 to 85	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to 150	°C
Maximum Output Current, Pin 4	Ι <sub>Ο</sub>	10	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

# Table 2. ATTRIBUTES

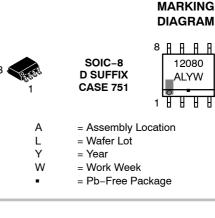
Characterist	Value		
ESD Protection	Human Body Model Machine Model	> 1500 V > 100 V	
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)		Level 1	
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test			

1. For additional information, see Application Note AND8003/D.

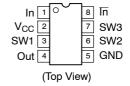


# **ON Semiconductor®**

http://onsemi.com



PIN CONNECTIONS



# FUNCTION TABLE

SW1	SW2	SW3	Divide Ratio
L	L	L	80
L	L	Н	40
L	Н	L	40
L	Н	Н	20
Н	L	L	40
Н	L	Н	20
Н	Н	L	20
Н	Н	Н	10

NOTE: SW1, SW2 and SW3: H =  $V_{CC}$ , L = Open.

# **ORDERING INFORMATION**

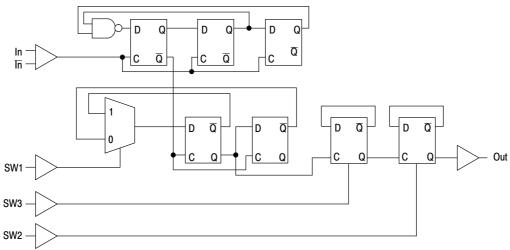
See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

# MC12080

Table 3. ELECTRICAL CHARACTERISTICS ( $V_{CC} = 4.5$ to 5.5 V; $T_A = -40$ to 85°C, unless otherwise noted.)
--

Characteristic	Symbol	Min	Тур	Max	Unit
Toggle Frequency (Sine Wave)	ft	0.1	1.4	1.1	GHz
Supply Current Output (Pin 2)	I <sub>CC</sub>	-	3.7	5.0	mA
Input Voltage Sensitivity 100 to 250 MHz 250 to 1100 MHz	V <sub>in</sub>	400 100	-	1000 1000	mVpp
Divide Ratio Control Input High (SW1, SW2, SW3)	V <sub>IH</sub>	V <sub>CC</sub> – 0.5 V	V <sub>CC</sub>	V <sub>CC</sub> + 0.5 V	V
Divide Ratio Control Input Low (SW1, SW2, SW3)	V <sub>IL</sub>	Open	Open	Open	-
$\begin{array}{l} \text{Output Voltage Swing (Note 1)} \\ \text{R}_L = 820 \ \Omega, \ \text{I}_O = 4.0 \ \text{mA for } \div 10 \\ \text{R}_L = 1.6 \ \text{k}\Omega, \ \text{I}_O = 2.1 \ \text{mA for } \div 20 \\ \text{R}_L = 3.3 \ \text{k}\Omega, \ \text{I}_O = 1.1 \ \text{mA for } \div 40 \\ \text{R}_L = 6.2 \ \text{k}\Omega, \ \text{I}_O = 0.57 \ \text{mA for } \div 80 \end{array}$	V <sub>out</sub>	0.8	1.2	-	V <sub>pp</sub>

1. Assumes 8.0 pF load and 1.1 GHz input frequency (typical),  $I_0$  at  $V_{CC}$  = 5.0 V and  $T_A$  = 25°C.





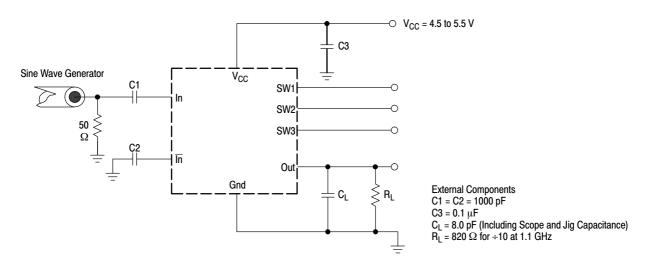
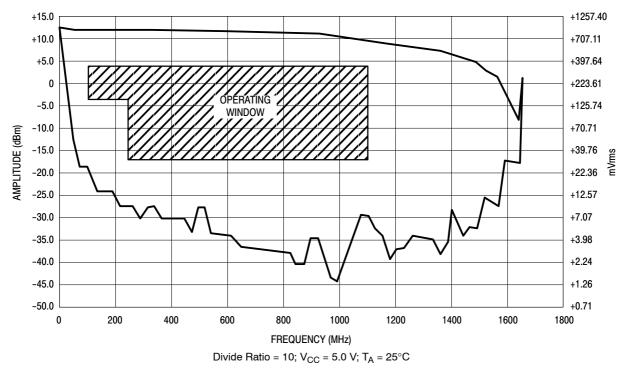
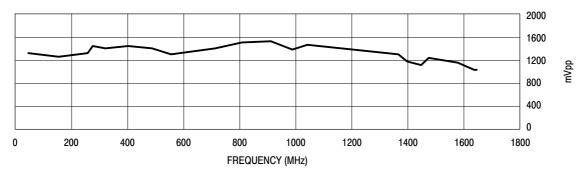


Figure 2. AC Test Circuit

MC12080









## **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
MC12080DG SOIC-8 98 Units / Rai		98 Units / Rail
MC12080DR2G	(Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# onsemí



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42564B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION: SOIC-8 NB PA			PAGE 1 OF 2		
the right to make changes without furth purpose, nor does <b>onsemi</b> assume ar	onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.				

#### SOIC-8 NB CASE 751-07 **ISSUE AK**

STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5.

6.

7.

8 GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. GATE, #2 5. SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 ANODE 1 3 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT OVI O 2 UVLO З. 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 З. BASE #2 COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

DOCUMENT NUMBER:	98ASB42564B Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOIC-8 NB		PAGE 2 OF 2

onsem and of isor in are trademarks or semiconductor compension instructions, the do onsem or its subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced states and/or outrofts, or non-emitting the subsidiaries in the oniced stat purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

7.

8

COLLECTOR, #1

COLLECTOR, #1

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>